End of Life January-2018 - Alternative Device: CNY17



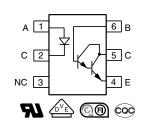
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H11B1, H11B2, H11B3

Vishay Semiconductors

Optocoupler, Photodarlington Output, High Gain, With Base Connection





DESCRIPTION

The H11B1, H11B2, H11B3 are industry standard optocouplers, consisting of a gallium arsenide infrared LED and a silicon photodarlington.

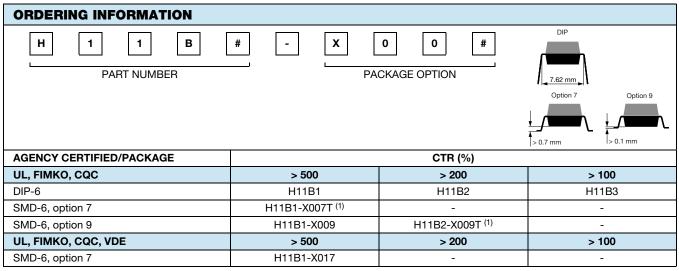
FEATURES

- Isolation test voltage: 4420 V_{RMS}
- Coupling capacitance, 0.5 pF
 Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



AGENCY APPROVALS

- UL1577, file no. E52744
- cUL tested to CSA 22.2 bulletin 5A
- DIN EN 60747-5-5 (VDE 0884-5) available with option 1
- FIMKO EN60065, EN60950-1
- CQC: GB8898-2011, GB4943.1-2011



Notes

• Additional options may be possible, please contact sales office.

⁽¹⁾ Also available in tubes, no "T" in the end.

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
INPUT							
Reverse voltage		V _R	3	V			
Forward continuous current		I _F	60	mA			
Power dissipation		P _{diss}	100	mW			
Derate linearly from 25 °C			1.33	mW/°C			
OUTPUT				-			
Collector emitter breakdown voltage		BV _{CEO}	25	V			
Emitter collector breakdown voltage		BV _{ECO}	7	V			
Collector base breakdown voltage		BV _{CBO}	30	V			
Collector current (continuous)		I _C	100	mA			
Power dissipation		P _{diss}	150	mW			
Derate linearly from 25 °C			2	mW/°C			

Rev. 1.8, 23-Jul-15

1 For technical questions, contact: <u>optocoupleranswers@vishay.com</u> Document Number: 83609

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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
COUPLER						
Total package dissipation (LED plus detector)		P _{tot}	260	mW		
Derate linearly from 25 °C			3.5	mW/°C		
Storage temperature		T _{stg}	-55 to +150	°C		
Operating temperature		T _{amb}	-55 to +100	°C		
Lead soldering time at 260 °C			10	S		

Note

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT							
	L 50 m A	H11B1	V _F	-	1.1	1.5	V
Forward voltage	I _F = 50 mA	H11B2	V _F	-	1.1	1.5	V
	I _F = 10 mA	H11B3	V _F	-	1.1	1.5	V
Reverse current	V _R = 3 V		I _R	-	-	10	μA
Junction capacitance	$V_F = 0 V, f = 1 MHz$		Cj	-	50	-	pF
OUTPUT							
Collector emitter breakdown voltage	$I_{\rm C}$ = 1 mA, $I_{\rm F}$ = 0 mA		BV _{CEO}	30	-	-	V
Emitter collector breakdown voltage	$I_{E} = 100 \mu A, I_{F} = 0 \text{ mA}$		BV _{ECO}	7	-	-	V
Collector base breakdown voltage	$I_{C} = 100 \ \mu A, I_{F} = 0 \ mA$		BV _{CBO}	30	-	-	V
Collector emitter leakage current	$V_{CE} = 10 \text{ V}, \text{ I}_{F} = 0 \text{ mA}$		I _{CEO}	-	-	100	nA
COUPLER							
Saturation voltage collector-emitter	I _F = 1 mA, I _C = 1 mA		V _{CEsat}	-	-	1	V
Capacitance (input to output)			C _{IO}	-	0.5	-	pF

Note

• Minimum and maximum values were tested requirements. Typical values are characteristics of the device and are the result of engineering evaluations. Typical values are for information only and are not part of the testing requirements

CURRENT TRANSFER RATIO (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
DC current transfer ratio	V _{CE} = 5 V, I _F = 1 mA	H11B1	CTR _{DC}	500			%
		H11B2	CTR _{DC}	200			%
		H11B3	CTR _{DC}	100			%

SWITCHING CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION SYMBOL MIN. TYP. MAX				MAX.	UNIT
Switching times	I_{F} = 5 mA, V_{CE} = 10 V, R_{L} = 100 Ω	t _{on}		5		μs
		t _{off}		30		μs

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SAFETY AND INSULATION RATINGS						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Climatic classification	According to IEC 68 part 1		55 / 100 / 21			
Comparative tracking index		CTI	175			
Maximum rated withstanding isolation voltage	t = 1 min	V _{ISO}	4420	V _{RMS}		
Maximum transient isolation voltage		VIOTM	10 000	V _{peak}		
Maximum repetitive peak isolation voltage		V _{IORM}	890	V _{peak}		
Isolation resistance	$V_{IO} = 500 \text{ V}, \text{ T}_{amb} = 25 ^{\circ}\text{C}$	R _{IO}	≥ 10 ¹²	Ω		
Isolation resistance	$V_{IO} = 500 \text{ V}, \text{ T}_{amb} = 100 ^{\circ}\text{C}$	R _{IO}	≥ 10 ¹¹	Ω		
Output safety power		P _{SO}	400	mW		
Input safety current		I _{SI}	275	mA		
Safety temperature		T _S	175	°C		
Creepage distance			≥7	mm		
Clearance distance			≥7	mm		
Insulation thickness		DTI	≥ 0.4	mm		

Note

As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with
the safety ratings shall be ensured by means of protective circuits

TYPICAL CHARACTERISTICS (Tamb = 25 °C, unless otherwise specified)

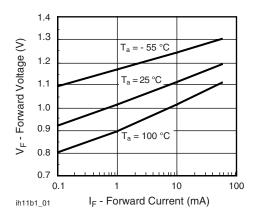


Fig. 1 - Forward Voltage vs. Forward Current

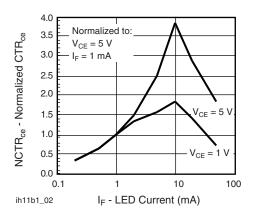


Fig. 2 - Normalized Non-Saturated and Saturated $\mbox{CTR}_{\mbox{CE}}$ vs. LED Current

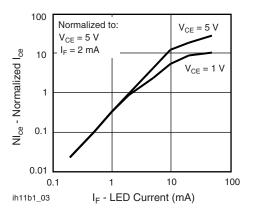


Fig. 3 - Normalized Non-Saturated and Saturated I_{CE} vs. LED Current

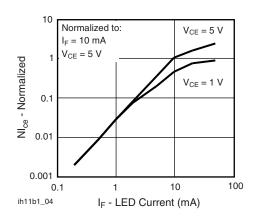


Fig. 4 - Normalized Non-Saturated and Saturated Collector Emitter Current vs. LED Current

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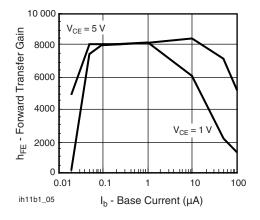


Fig. 5 - Non-Saturated and Saturated hFE vs. Base Current

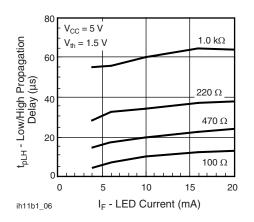
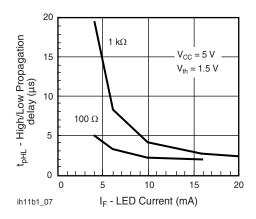


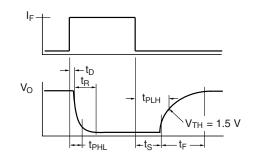
Fig. 6 - Low to High Propagation Delay vs. Collector Load Resistance and LED Current



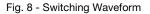


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ih11b1_08



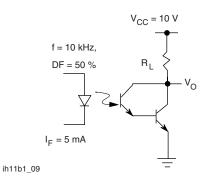


Fig. 9 - Switching Schematic

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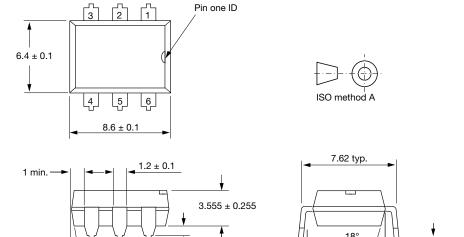


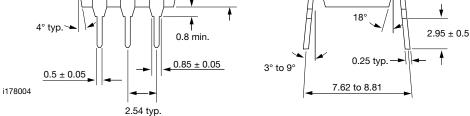
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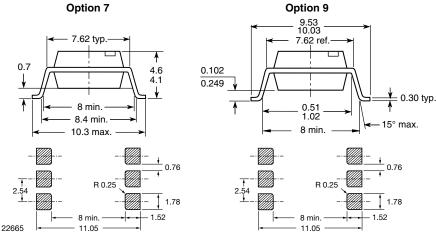
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PACKAGE DIMENSIONS in millimeters

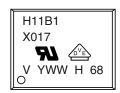




Option 7



PACKAGE MARKING (example)



Notes

- Only options 1, 7, and 9 are reflected in the package marking
- The VDE logo is only marked on option 1 parts
- Tape and reel suffix (T) is not part of the package marking ٠



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